

MM74HC123A

Dual Retriggerable Monostable Multivibrator

General Description

The MM74HC123A high speed monostable multivibrators (one shots) utilize advanced silicon-gate CMOS technology. They feature speeds comparable to low power Schottky TTL circuitry while retaining the low power and high noise immunity characteristic of CMOS circuits.

Each multivibrator features both a negative, A, and a positive, B, transition triggered input, either of which can be used as an inhibit input. Also included is a clear input that when taken low resets the one shot. The MM74HC123A can be triggered on the positive transition of the clear while A is held LOW and B is held HIGH.

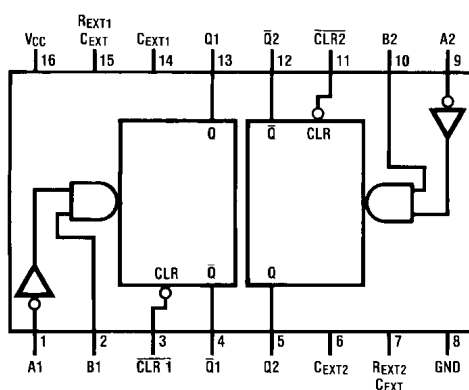
The MM74HC123A is retriggerable. That is it may be triggered repeatedly while their outputs are generating a pulse and the pulse will be extended.

Pulse width stability over a wide range of temperature and supply is achieved using linear CMOS techniques. The output pulse equation is simply: $PW = (R_{EXT}) (C_{EXT})$; where PW is in seconds, R is in ohms, and C is in farads. All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

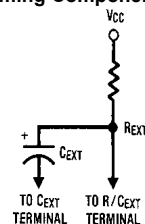
- Typical propagation delay: 25 ns
- Wide power supply range: 2V–6V
- Low quiescent current: 80 μ A maximum (74HC Series)
- Low input current: 1 μ A maximum
- Fanout of 10 LS-TTL loads
- Simple pulse width formula $T = RC$
- Wide pulse range: 400 ns to ∞ (typ)
- Part to part variation: $\pm 5\%$ (typ)
- Schmitt Trigger A & B inputs allow rise and fall times to be as slow as one second

Connection Diagram



Top View

Timing Component



Note: Pin 6 and Pin 14 must be hard-wired to GND.

Rochester Ordering Guide







*Most products can also be offered as RoHS compliant, designated by a –G suffix. Please contact factory for more information.

Rochester Part Number	Fairchild Part Number	Package	Temperature
MM74HC123AN	MM74HC123AN	PDIP-16	-40° to +85°C
MM74HC123AM	MM74HC123AM	SOP-16, Plastic	-40° to +85°C
MM74HC123AMTC	MM74HC123AMTC	TSSOP-16, Plastic	-40° to +85°C
MM74HC123ASJ	MM74HC123ASJ	SOP-16, Plastic	-40° to +85°C

Please contact factory for specific package availability and Military/Aerospace specifications/availability.

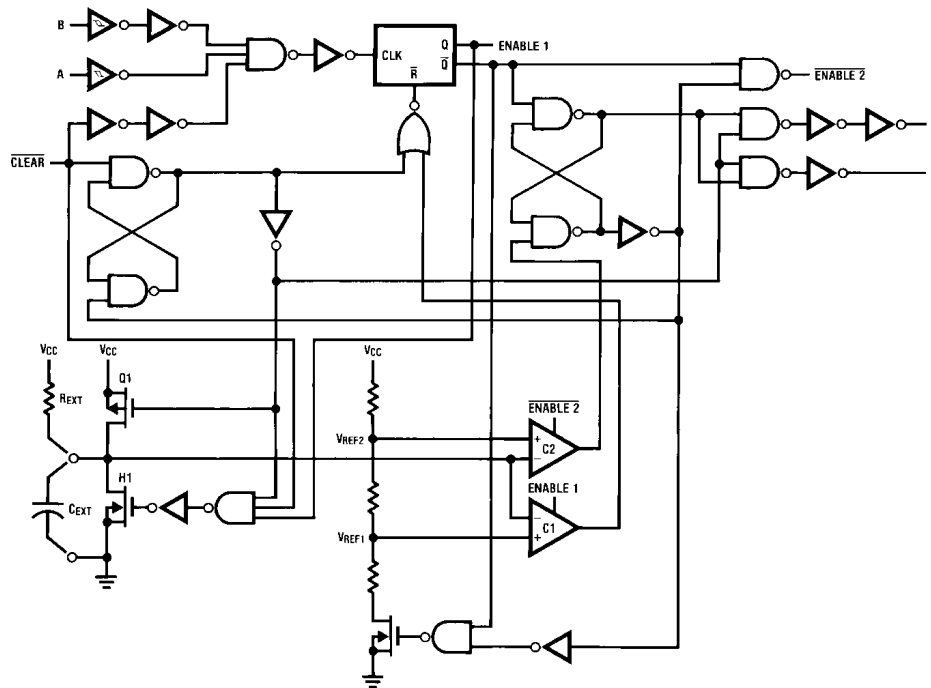
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Truth Table

Inputs			Outputs	
$\overline{\text{Clear}}$	A	B	Q	\overline{Q}
L	X	X	L	H
X	H	X	L	H
X	X	L	L	H
H	L	\uparrow		
H	\downarrow	H		
\uparrow	L	H		

H = HIGH Level
L = LOW Level
↑ = Transition from LOW-to-HIGH
↓ = Transition from HIGH-to-LOW
⌋ = One HIGH Level Pulse
⌋ = One LOW Level Pulse
X = Irrelevant

Logic Diagram



74HC123A

Absolute Maximum Ratings (Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_{IN})	−1.5V to $V_{CC} + 1.5V$
DC Output Voltage (V_{OUT})	−0.5V to $V_{CC} + 0.5V$
Clamp Diode Current (I_{IK} , I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN} , V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times (Clear Input)			
(t_r , t_f) $V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns

Note 1: Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation Temperature Derating: Plastic "N" Package: −12mW/°C from 65°C to 85°C

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		T _A = −40 to 85°C	T _A = −55 to 125°C	Units
				Typ	Guaranteed Limits			
V _{IH}	Minimum HIGH Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V _{IL}	Maximum LOW Level Input Voltage		2.0V		0.3	0.3	0.3	V
			4.5V		0.9	0.9	0.9	V
			6.0V		1.2	1.2	1.2	V
V _{OH}	Minimum HIGH Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 4.0 mA I _{OUT} ≤ 5.2 mA	4.5V	4.2	3.98	3.84	3.7	V
			6.0V	5.7	5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 4 mA I _{OUT} ≤ 5.2 mA	4.5V	0.2	0.26	0.33	0.4	V
			6.0V	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input Current (Pins 7, 15)	V _{IN} = V _{CC} or GND	6.0V		±0.5	±5.0	±5.0	μA
I _{IN}	Maximum Input Current (all other pins)	V _{IN} = V _{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I _{CC}	Maximum Quiescent Supply Current (standby)	V _{IN} = V _{CC} or GND I _{OUT} = 0 μA	6.0V		8.0	80	160	μA
I _{CC}	Maximum Active Supply Current (per monostable)	V _{IN} = V _{CC} or GND R/C _{EXT} = 0.5V _{CC}	2.0V	36	80	110	130	μA
			4.5V	0.33	1.0	1.3	1.6	mA
			6.0V	0.7	2.0	2.6	3.2	mA

Note 4: For a power supply of $5V \pm 10\%$ the worst-case output voltages (V_{OH} , V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst-case V_{IH} and V_{IL} occur at $V_{CC} = 5.5V$ and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst-case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

$V_{CC} = 5V$, $T_A = 25^\circ C$, $C_L = 15\text{ pF}$, $t_r = t_f = 6\text{ ns}$

Symbol	Parameter	Conditions	Typ	Limit	Units
t_{PLH}	Maximum Trigger Propagation Delay A, B or Clear to Q		22	33	ns
t_{PHL}	Maximum Trigger Propagation Delay A, B or Clear to \overline{Q}		25	42	ns
t_{PHL}	Maximum Propagation Delay, Clear to Q		20	27	ns
t_{PLH}	Maximum Propagation Delay, Clear to \overline{Q}		22	33	ns
t_W	Minimum Pulse Width, A, B or Clear		14	26	ns
t_{REM}	Minimum Clear Removal Time			0	ns
$t_{WQ(MIN)}$	Minimum Output Pulse Width	$C_{EXT} = 28\text{ pF}$ $R_{EXT} = 2\text{ k}\Omega$	400		ns
t_{WQ}	Output Pulse Width	$C_{EXT} = 1000\text{ pF}$ $R_{EXT} = 10\text{ k}\Omega$	10		μs

AC Electrical Characteristics

$C_L = 50\text{ pF}$, $t_r = t_f = 6\text{ ns}$ (unless otherwise specified)

Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		T _A = −40 to 85°C	T _A = −55 to 125°C	Units	
				Typ	Guaranteed Limits				
t _{PLH}	Maximum Trigger Propagation Delay, A, B or Clear to Q		2.0V	77	169	194	210	ns	
			4.5V	26	42	51	57	ns	
			6.0V	21	32	39	44	ns	
t _{PHL}	Maximum Trigger Propagation Delay, A, B or Clear to \overline{Q}		2.0V	88	197	229	250	ns	
			4.5V	29	48	60	67	ns	
			6.0V	24	38	46	51	ns	
t _{PHL}	Maximum Propagation Delay Clear to Q		2.0V	54	114	132	143	ns	
			4.5V	23	34	41	45	ns	
			6.0V	19	28	33	36	ns	
t _{PLH}	Maximum Propagation Delay Clear to \overline{Q}		2.0V	56	116	135	147	ns	
			4.5V	25	36	42	46	ns	
			6.0V	20	29	34	37	ns	
t _W	Minimum Pulse Width A, B, Clear		2.0V	57	123	144	157	ns	
			4.5V	17	30	37	42	ns	
			6.0V	12	21	27	30	ns	
t _{REM}	Minimum Clear Removal Time		2.0V		0	0	0	ns	
			4.5V		0	0	0	ns	
			6.0V		0	0	0	ns	
t _{TLH} , t _{THL}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns	
			4.5V	8	15	19	22	ns	
			6.0V	7	13	16	19	ns	
t _{WQ(MIN)}	Minimum Output Pulse Width	C _{EXT} = 28 pF	2.0V	1.5				μs	
		R _{EXT} = 2 kΩ	4.5V	450				ns	
		R _{EXT} = 6 kΩ (V _{CC} = 2V)	6.0V	380				ns	
t _{WQ}	Output Pulse Width	C _{EXT} = 0.1 μF	Mn	5.0V	1	0.9	0.86	0.85	ms
		R _{EXT} = 10 kΩ	Mx	5.0V	1	1.1	1.14	1.15	ms
C _{IN}	Maximum Input Capacitance (Pins 7 & 15)			12	20	20	20	pF	
C _{IN}	Maximum Input Capacitance (other inputs)			6	10	10	10	pF	
C _{PD}	Power Dissipation Capacitance	(Note 5)		70				pF	

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

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